Present Status and Prospects for Fuji Electric IC Technology

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1. Introduction

Fuji Electric ICs (integrated circuits) are specialized for specific applications, and have been developed based on distinguished technologies. For example, we have used high-voltage technology [C/DMOS (complementary/double diffused metal-oxide semiconductor) technology] and sensor technology (photodiodes and piezoelectric resistance sensors) to develop controller ICs for power supplies, flat panel display driver ICs (for plasma and liquid crystal displays), auto-focus ICs for cameras, and pressure sensors and hybrid ICs for automobiles.

The semiconductor market has been subjected to boom-and-bust cycles and there is fierce competition. To survive in this environment, it is important for us to refine the distinguished technologies and develop core technologies to supply unique products not available from other companies. An outline of our technologies, examples of our products, and future prospects are described below.

2. Present Status of Fuji Electric ICs

2.1 Process/device technologies

Characteristic features of Fuji Electric's process and device technologies are high voltage and analogdigital hybrid technology. Processes to achieve fine machining as well as high voltage have been developed, and methods of improving analog precision have been developed. Typical processes are as follows (Fig. 1).

(1) Bipolar IC

Because of low cost and high precision, this process has been used for controller ICs in automobile ignition systems, pressure sensors, and ICs for power supplies. (2) Si-gate CMOSIC

This process, a leader in fine machining, developed into a process for standard logic (5V class) and then into a process for higher voltage ICs. Mass production of CMOSICs with a 0.6μ m design rule has been realized. CMOSICs are widely used as analog-digital hybrid ICs for power supplies, cellular phones, automatic focusing, and liquid crystal display drivers. This paper introduces high-voltage CMOSIC technology (30V, 60V, and 120V).

(3) C/DMOSIC

This hybrid process combines DMOS technology with a Si-gate CMOS high-voltage construction and is used for power supply ICs and plasma display driver ICs. This is an effective technology to reduce the size of built-in power MOSFETs (metal-oxide-semiconductor field-effect transistors). Figure 2 shows the DMOSIC on-resistance area efficiency. This paper introduces the plasma display driver IC that uses dielectric isolation technology (SOI) as an example.

In addition, Fuji Electric possesses a bump process (solder and gold) suitable for Bi-CMOSIC and bear chip assembly and can satisfy various customer requests.

2.2 Packaging technology

Plastic molded packages, including DIP (dual inline package), SOP (small outline package), QFP (quad flat package) and TSSOP (thin shrink SOP), fine-pitch and thin packages, are available. CSP (chip size package) is also being investigated. As mentioned before, Fuji Electric possesses a bump process suitable for bear chip assembly and has the complete assembly



Fig.1 Fuji Electric IC process technology

Fig.2 On-resistance area efficiency of Fuji Electric DMOSICs









technologies to miniaturize packages (Fig. 3).

Fuji Electric also possesses technologies for modules with lenses and clear resin molded packages for autofocus ICs, and provides a series of high-reliability metal packages and resin-sealed packages for pressure sensors.

2.3 Fuji Electric ICs

Having started from full-custom ICs, Fuji Electric product development is now focusing on application specific standard product (ASSP) ICs.

A typical product is the power supply IC. In response to the need for resource and energy conservation for global environment protection, a low power consumption CMOS and a power factor correction IC series have been developed (Fig. 4 and Table 1).

Regarding autofocus ICs for cameras, a series of modules with lenses have been developed, and the development of small modules suitable for thin cameras (APS) and low-priced analog sensors (in addition to the conventional digital sensors) has been completed

Fig.5 Fuji Electric autofocus IC modules



(Fig. 5 and Table 2).

The color plasma display driver IC has been used to produce large-screen TVs and monitors. This paper introduces an advanced product line of small liquid crystal controllers, as well as pressure sensors used for diesel engines.

Table 1 Fuji Electric ICs for power supplies (a) AC-DC converter

\square	Item			Application circuits			MOSEET	Mode		Protection circuit			
Classification		Type number	Dmax	Flyback	Forward	Power factor correction	drive	Voltage	Current	OCP	OVP	OTP	Number of pins
For control- lers	Bipolar IC	FA5301	100%	0				0		0			16 pins
		FA5304	46%		0		0	0		0	0		8 pins
		FA5305	46%		0		0	0		0	\bigcirc		8 pins
		FA5310	46%		0		0	0		0	\bigcirc		8 pins
		FA5311	70%	0			0	0		0	\bigcirc		8 pins
		FA5314	46%		0		0	0		0	0		8 pins
		FA5315	70%	0			0	0		0	0		8 pins
		FA5316	46%		0		0	0		0	0		8 pins
		FA5317	70%	0			0	0		0	0		8 pins
		FA5321	50%		0		0		0	0	\bigcirc	0	16 pins
		FA5331	92%			0	0			0	\bigcirc		16 pins
		FA5332	92%			0	0			0	\bigcirc		16 pins
	MOSIC	FA13842	96%	0			0		0				8 pins
		FA13844	48%		0		0		0				8 pins

(b) DC-DC converter

Item Classification		Type number	Number of channels	Voltage control range				Application circuits			MOS-	Number
				2.5 to 22V	3.6 to 22V	1.4 to 12V	10 to 50V	Step- down	Step- up	Up & down	FET drive	of pins
For control- lers	Bipolar IC	FA7610	1		0				0	0		8 pins
		FA7611	2		0			0	0	0		16 pins
		FA7612	1		0			0				8 pins
		FA7613	1	0				0		\bigcirc		16 pins
		FA7615	2		0			0	\bigcirc	\bigcirc		16 pins
		FA7616	2			0			\bigcirc	\bigcirc		16 pins
		FA7617	1		0					\bigcirc		8 pins
		FA7622	2		0			0	0	0	0	20 pins
		FA7630	2		0			\bigcirc		\bigcirc	\bigcirc	20 pins
	MOSIC	FA3630	2	0				\bigcirc	0	\bigcirc	\bigcirc	16 pins
		FA13843	1						\bigcirc	\bigcirc	\bigcirc	8 pins
		FA13845	1						0	0	\bigcirc	8 pins
For con- trollers with a built-in MOSFET	MOSIC	FA3621	6					\bigcirc	\bigcirc	\bigcirc	\bigcirc	8 pins
		FA3629	3		0				0	0	\bigcirc	16 pins
		FA36XX	1				0	0				8 pins

Table 2 Fuji Electric autofocus ICs

Type Application	Digital sensor, 21µm-pitch	Analog sensor, 21µm-pitch	Analog sensor, 12µm-pitch
Zoom of $3 \times$ or less	FM6234T	FM6254T	FM6255T
Zoom of 3× or greater	FM6232T	FM6252T	(FM6256T)

Note: Products enclosed in parentheses are "under development".

3. Future Prospects

For Fuji Electric ICs to survive in the future, as a matter of course, they must satisfy market needs. Further, it is necessary that they possess unique technology not available from other companies as well as flexible design technology to comply with diversified requirements within a short time. Fuji Electric is working to introduce an IP (intellectual property) core and to develop CAD (computer-aided design) technology, presented in this paper as system design technology.

4. Conclusion

The present status and prospects for Fuji Electric's IC technology have been described. Further with our characteristic technologies, we will continue to develop and supply products that satisfy user needs.



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